



FMMT493A

#### 120V NPN SILICON PLANAR MEDIUM POWER TRANSISTOR IN SOT23 (Type DN)

#### **Feature**

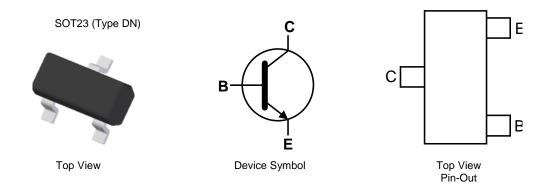
- BV<sub>CEO</sub> > 60V
- I<sub>C</sub> = 1A Continuous Collector Current
- VCE<sub>SAT</sub> = 0.5V @1A
- 500mW Power Dissipation
- Low Saturation Voltage
- High h<sub>FE</sub> Min 300@250mA
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT23 (Type DN)
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)

#### **Applications**

- Various Driving Functions Including Motors, Actuators, Solenoid and Relays
- Backlight Inverters
- DC-DC Modules



# Ordering Information (Note 4)

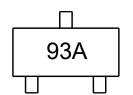
Ī	Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
	FMMT493ATA	AEC-Q101	93A	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**

SOT23 (Type DN)



93A = Product Type Marking Code



### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	120	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	1	Α
Peak Pulse Current	I <sub>CM</sub>	2	Α
Base Current	Ι <sub>Β</sub>	200	mA

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	500	mW
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>0JA</sub>	250	°C/W
Thermal Resistance, Junction to Lead (Note 6)	$R_{ heta JL}$	197	°C/W
Operating and Storage Temperature Range	T <sub>J.</sub> T <sub>STG</sub>	-55 to +150	°C

# ESD Ratings (Note 7)

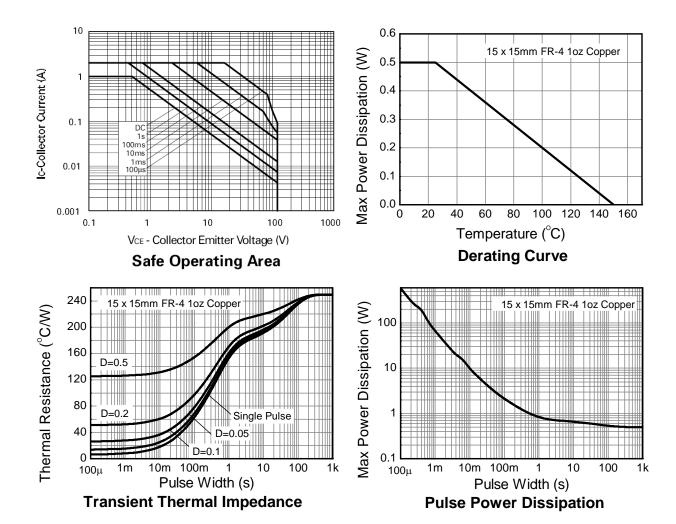
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Notes:

- 5. For a device surface mounted on 15mm X 15mm FR-4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
- 6. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**





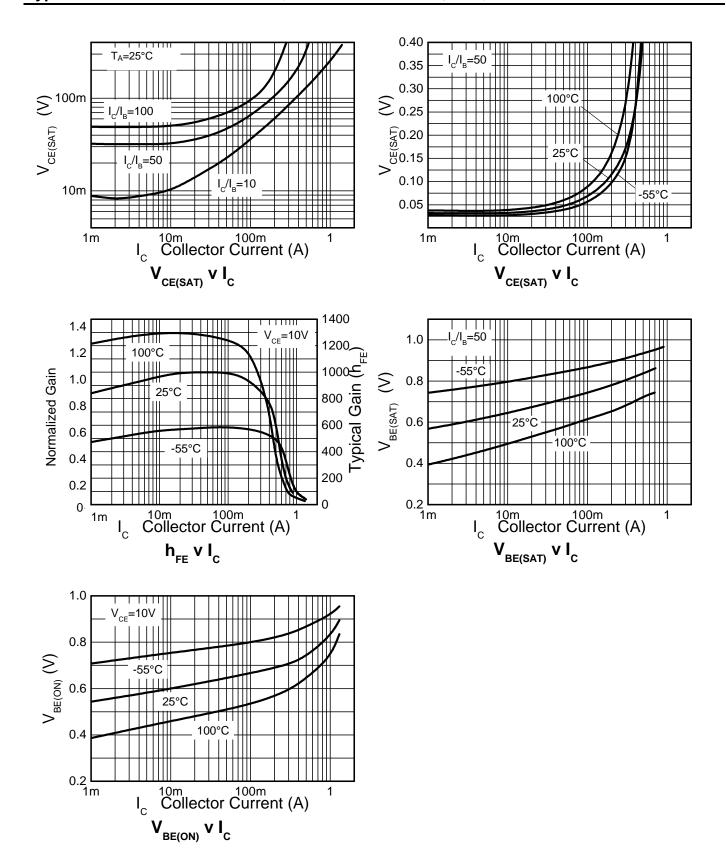
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	120			V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 8)	BV <sub>CEO</sub>	60		_	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7		_	V	$I_{E} = 100 \mu A$
Collector Cutoff Current	I <sub>CBO</sub>	_		100	nA	$V_{CB} = 45V$
Emitter Cutoff Current	I <sub>EBO</sub>	_		100	nA	$V_{EB} = 4V$
Collector Emitter Cutoff Current	I <sub>CES</sub>	_		100	nA	V <sub>CE</sub> = 45V
	hFE	300				$I_C = 1mA$ , $V_{CE} = 10V$
		500		-		I <sub>C</sub> = 150mA, V <sub>CE</sub> = 10V
Static Forward Current Transfer Ratio (Note 8)		300		1200		I <sub>C</sub> = 250mA, V <sub>CE</sub> = 10V
		100		_		$I_C = 500 \text{mA}, V_{CE} = 10 \text{V}$
		20		-		I <sub>C</sub> = 1A, V <sub>CE</sub> = 10V
Collector-Emitter Saturation Voltage (Note 8)	V <sub>CE(SAT)</sub>	_		250	mV	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$
Collector-Emilier Saturation voltage (Note 8)		_		500	IIIV	$I_C = 1A$ , $I_B = 100mA$
Base-Emitter Turn-On Voltage (Note 8)	$V_{BE(ON)}$	_		1.0	V	$I_C = 1A, V_{CE} = 10V$
Base-Emitter Saturation Voltage (Note 8)	$V_{BE(SAT)}$	_		1.15	V	$I_C = 1A, I_B = 100mA$
Output Capacitance	$C_{obo}$	_		10	pF	$V_{CB} = 10V$ , $f = 1MHz$
Transition Frequency	f <sub>T</sub>	150	_		MHz	$V_{CE} = 10V, I_{C} = 50mA,$ f = 100MHz

Notes: 8. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

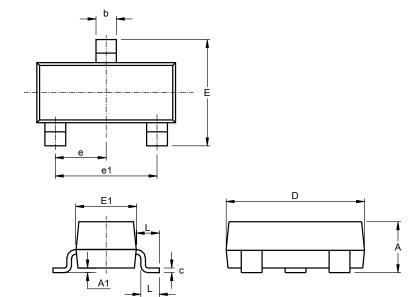




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23 (Type DN)

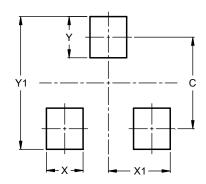


SOT23 (Type DN)						
Dim	Min	Max	Тур			
Α	0.89	1.12	1.00			
A1	0.01	0.10	0.05			
b	0.30	0.51	0.45			
С	0.08	0.20	0.10			
D	2.80	3.04	3.00			
Е	2.10	2.64	2.42			
<b>E1</b> 1.20		1.40	1.37			
е	0.95 REF					
e1	1.90 REF					
L	0.25	0.60	0.30			
L1	0.45	0.62	0.54			
All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23 (Type DN)



Dimensions	Value (in mm)			
С	2.0			
Х	0.8			
X1	1.35			
Y	0.9			
Y1	2.9			



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